

FMP20N60S1

FUJI POWER MOSFET

Super J-MOS series

N-Channel enhancement mode power MOSFET

■ Features

Low on-state resistance Low switching loss easy to use (more controllabe switching dV/dt by Rg)

Applications

UPS

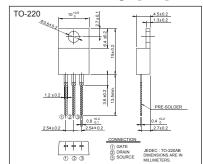
Server

Telecom

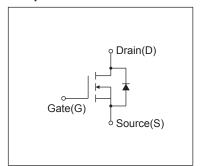
Power conditioner system

Power supply

■ Outline Drawings [mm]



■ Equivalent circuit schematic



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings at T_c=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks	
Drain Source Voltage	V _{DS}	600	V		
Drain-Source Voltage	V _{DSX}	600	V	V _{GS} =-30V	
Continuous Drain Current	lo	±20	Α	Tc=25°C Note*1	
		±12.6	Α	Tc=100°C Note*1	
Pulsed Drain Current	IDP	±60	Α		
Gate-Source Voltage	V _G s	±30	V		
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	6.6	Α	Note *2	
Non-Repetitive Maximum Avalanche Energy	Eas	472.2	mJ	Note *3	
Maximum Drain-Source dV/dt	dV _{DS} /dt	50	kV/μs	V _{DS} ≤ 600V	
Peak Diode Recovery dV/dt	dV/dt	15	kV/μs	Note *4	
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note *5	
Maximum Power Dissipation	PD	2.02	10/	Ta=25°C	
		150	W	Tc=25°C	
Onereting and Stayons Temporature rooms	Tch	150	°C		
Operating and Storage Temperature range	T _{stg}	-55 to +150	°C		

Note *1 : Limited by maximum channel temperature.

Note *1: Limited by maximum channel temperature. Note *2: T_{rb}≤150°C, See Fig.1 and Fig.2 Note *3: Starting T_{ch}=25°C, I_s=2A, L=216mH, V_{DD}=60V, R_G=50 Ω , See Fig.1 and Fig.2 Eas limited by maximum channel temperature and avalanche current. Note *4: I_F≤-I_D, -di/dt=100A/µs, V_{DD}≤400V, T_{ch}≤150°C. Note *5: I_F≤-I_D, dV/dt=15kV/µs, V_{DD}≤400V, T_{ch}≤150°C.

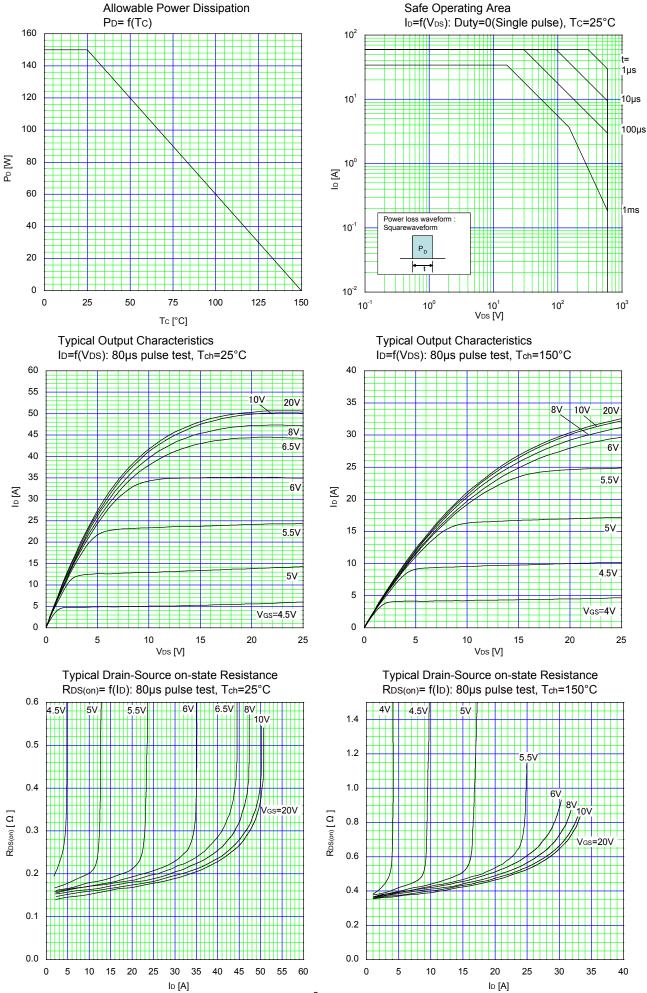
● Electrical Characteristics at T₀=25°C (unless otherwise specified) Static Ratings

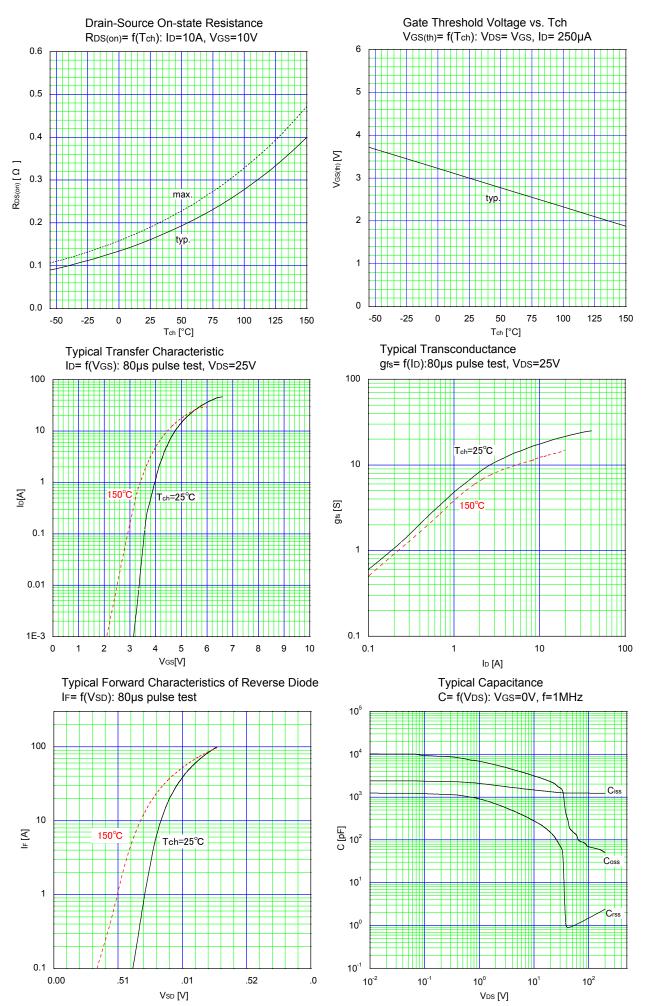
Description	Symbol	Conditions		min.	typ.	max.	Unit	
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA V _{GS} =0V		600	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	I _D =250μA V _{DS} =V _{GS}		2.5	3	3.5	V	
Zero Gate Voltage Drain Current	Ipss	V _{DS} =600V V _{GS} =0V	T _{ch} =25°C	-	-	25	μA	
		V _{DS} =480V V _{GS} =0V	T _{ch} =125°C	-	-	250		
Gate-Source Leakage Current	Igss	V _{SS} = ± 30V V _{DS} =0V		-	10	100	nA	
Drain-Source On-State Resistance	R _{DS(on)}	I _D =10A V _{GS} =10V		-	0.161	0.19	Ω	
Gate resistance	Rg	f=1MHz, open drain	f=1MHz, open drain		3.7	-	Ω	
Forward Transconductance	g _{fs}	I _D =10A V _{DS} =25V		8.5	17.5	-	S	
Input Capacitance	Ciss	V _{DS} =10V	V _{DS} =10V		1470	-		
Output Capacitance	Coss	V _{GS} =0V		-	3120	-		
Reverse Transfer Capacitance	Crss	f=1MHz	f=1MHz		280	-		
Effective output capacitance, energy related (Note *6)	C _{o(er)}	V _{GS} =0V V _{DS} =0480V		-	90	-	pF	
Effective output capacitance, time related (Note *7)	C _{o(tr)}	V _{GS} =0V V _{DS} =0480V ID=constant		-	305	-		
Turn-On Time	t _{d(on)}	V _{DD} =400V, V _{GS} =10V I _D =10A, R _G =27Ω See Fig.3 and Fig.4		-	22	-	ns	
	tr			-	40	-		
Turn-Off Time	t _{d(off)}			-	162	-		
	tr	See Fig.3 and Fig.4	-	22	-			
Total Gate Charge	Q _G	1001/1			48	-	nC	
Gate-Source Charge	Q _{GS}	V _{DD} =480V, I _D =20A		-	12.5	-		
Gate-Drain Charge	Q _{GD}		V _{cs} =10V See Fig.5		15	-		
Drain-Source crossover Charge	Qsw	000 Fig.5			8	-		
Avalanche Capability	lav	L=6.02mH, T _{ch} =25°C See Fig.1 and Fig.2		6.6	-	-	А	
Diode Forward On-Voltage	V _{SD}	I _F =20A, V _{GS} =0V T _{ch} =25°C		-	0.9	1.35	V	
Reverse Recovery Time	trr	I _F =20A, V _{GS} =0V V _{DD} =400V -di/dt=100A/µs T _{ch} =25°C See Fig.6			370	-	ns	
Reverse Recovery Charge	Qrr			-	6.2	-	μC	
Peak Reverse Recovery Current	Irp			-	32	-	А	

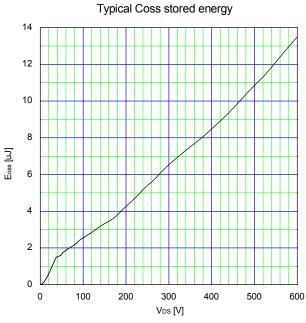
Note *6 : $C_{0(er)}$ is a fixed capacitance that gives the same stored energy as C_{0ss} while V_{DS} is rising from 0 to 80% BVoss. Note *7 : $C_{0(tr)}$ is a fixed capacitance that gives the same charging times as C_{0ss} while V_{DS} is rising from 0 to 80% BVoss.

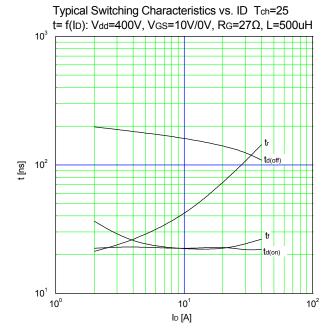
Thermal Characteristics

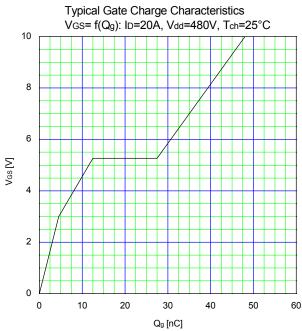
Description	Symbol	min.	typ.	max.	Unit
Channel to Case	R _{th(ch-c)}			0.83	°C/W
Channel to Ambient	Rth/ch-a)			62	°C/W

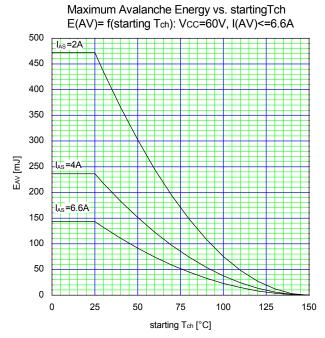


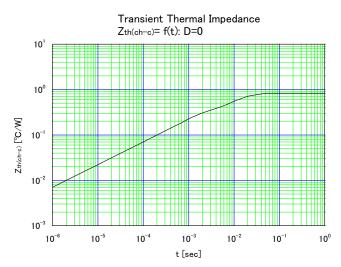




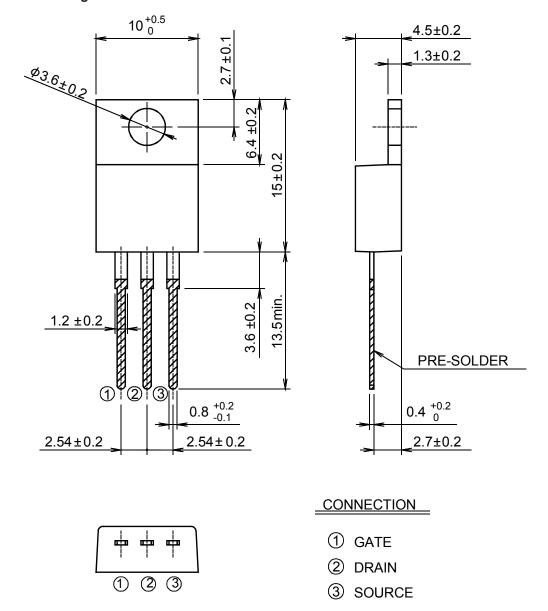








■ Outview: TO-220 Package



■ Marking

Country of origin mark.

" " (Blank): Japan
P : Philippines

Trademark

Trademark

Type name

Date code & Lot No.

Y: Last digit of year

M: Month code 1~9 and O,N,D

NNN: Lot. serial number

Under bar of date code

: means lead-free mark

JEDEC: TO-220AB

DIMENSIONS ARE IN MILLIMETERS.

^{*} The font (font type,size) and the trademark-size might be actually different.

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 - Computers
- OA equipment
- Communications equipment (terminal devices)
- Measurement equipment

- · Machine tools
- Audiovisual equipment Electrical home appliances
- Personal equipment Industrial robots etc.

· Gas leakage detectors with an auto-shut-off feature

Trunk communications equipment

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(without limitation). Space equipment

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